

# SILICON TRANSISTOR 2SA1714

# PNP SILICON EPITAXIAL POWER TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING

The 2SA1714 is a high-speed darlington power transistor. This transistor is ideal for high-precision control such as PWM control for pulse mortors or blushless mortor of OA and FA equipment.

#### **FEATURES**

- · High DC current amplifiers due to darlington connection
- Large current capacitance and low VCE(sat)
- TO-126 power transistor with high power dissipation
- · Complementary transistor with 2SC4342

#### **QUALITY GRADES**

Standard

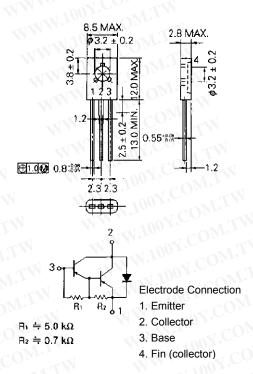
Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	-100	٧
Collector to emitter voltage	VCEO	-100	V
Emitter to base voltage	VEBO	-8.0	VV.
Collector current (DC)	Ic(DC)	∓3.0	Α
Collector current (pulse)	IC(pulse)*	∓6.0	Α
Base current (DC)	I <sub>B(DC)</sub>	-0.3	Α
Total power dissipation	P⊤ (Ta = 25°C)	1.3	W
Total power dissipation	P <sub>T</sub> (Tc = 25°C)	12	W
Junction temperature	Ti	150	°C \
Storage temperature	Tstg	-55 to +150	°C

<sup>\*</sup> PW ≤ 10 ms, duty cycle ≤ 50%

#### PACKAGE DRAWING (UNIT: mm)



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#### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.
Collector to emitter voltage	VCEO(SUS)	Ic = -3.0  A, IB = -3.0  mA, L = 1.0  mH	-100	Tir .	
Collector cutoff current	Ісво	V <sub>CB</sub> = -100 V, I <sub>E</sub> = 0	) Y. C	WIN	-10
Collector cutoff current	ICEO	VcE = -100 V, RBE = ∞	001.0	M.TN	-10
DC current gain	h <sub>FE1</sub> **	Vce = -2.0 V, Ic = -1.5 A	2,000	T.Mo.	20,000
DC current gain	hFE2**	Vce = -2.0 V, Ic = -3.0 A	1,000	· M.T	
Collector saturation voltage	VCE(sat)**	Ic = -1.5 A, Iв = -1.5 mA	100X	-0.9	-1.2
Base saturation voltage	V <sub>BE(sat)</sub> **	Ic = -1.5 A, Iв = -1.5 mA	100	-1.5	-2.0
Turn-on time	ton	Ic = $-1.5$ A, I <sub>B1</sub> = $-I_{B2}$ = $-1.5$ mA, R <sub>L</sub> = $33$ $\Omega$ , Vcc $\cong$ $-50$ V Refer to the test circuit.	W. 10	0.15	VT
Storage time	tstg		MM·I	1.2	NI.
Fall time	<b>t</b> f	neier to the test circuit.	WW.	0.6	OM.

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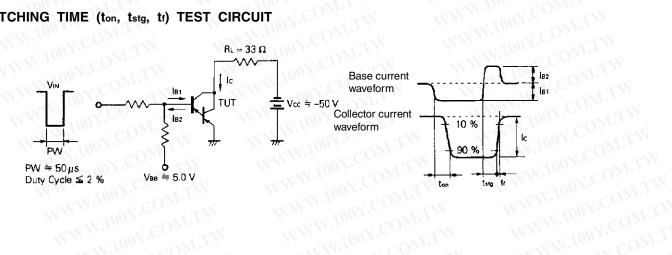
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#### **hfe CLASSIFICATION**

* Pulse test	$PW \le 350 \mu s$ , du	ty cycle ≤ 2%/puls	ed
hfe CLASS	IFICATION		
Marking	M	II W	N K
h <sub>FE1</sub>	2,000 to 5,000	4,000 to 10,000	8,000 to 20,000

# SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

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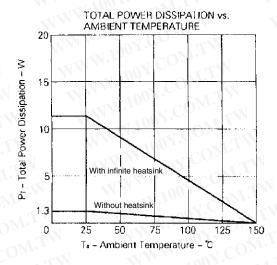
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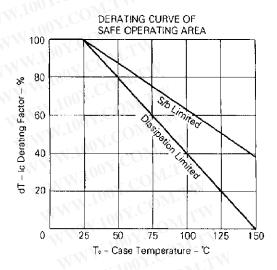
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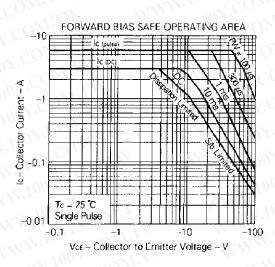
<sup>\*\*</sup> Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%/pulsed

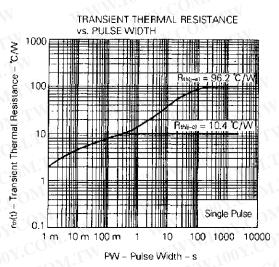


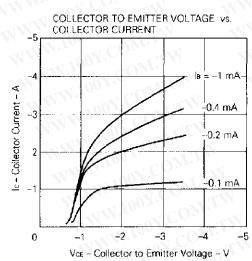
## TYPICAL CHARACTERISTICS (Ta = 25°C)

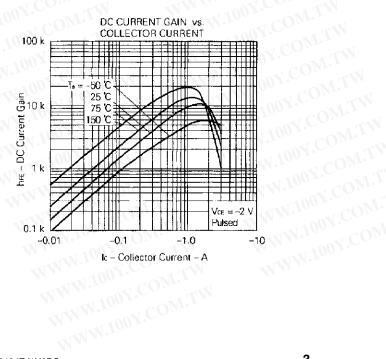




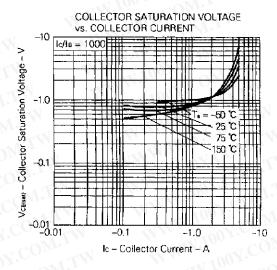


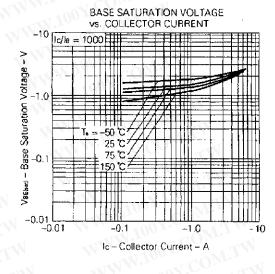


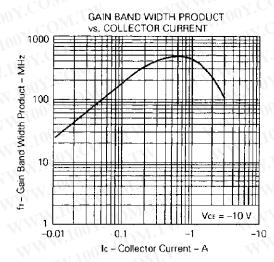


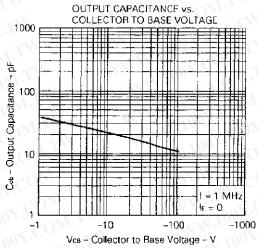


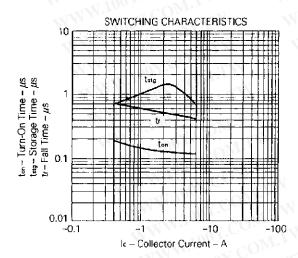
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